

 Drafts Pending Active

- L1: (3) (hybrid near microelectronic near memory) or Hybrid near molecular near memory
- L2: (588) (microelectronic near memory) or molecular near memory
- L3: (86) 2 and hybrid
- L4: (1) "5010451"; PN
- L5: (1) "10628989"
- L6: (180) "6128214"
- L7: (33) "6208553"
- L8: (1) ("6208553"); PN
- L9: (1) ("6212093"); PN
- L10: (6) ("3 and (substrate with dop\$3)"); PN
- L11: (25) 3 and (substrate with dop\$3)
- L12: (25) 3 and (substrate with dop\$3) and electrode
- L13: (24) 3 and (substrate with dop\$3) and switch and redox
- L14: (1) ("6212093"); PN
- L15: (1) ("6451942"); PN

 Failed Saved Favorites Tagged (0) UDC Queue Trash

Search	Groups	Topics	Case
<input type="text"/> US PGPUB USPAT EPO WO	<input type="checkbox"/> Filter		
<input type="text"/> Default operator: OR	<input type="checkbox"/> Highlight all relevant words		

3 and (substrate with dop\$3) and electrode and redox

	Document ID	Issue Date	Pages	Title	Current OR	Current XRef
1	<input type="checkbox"/> US 20050063210 A1	20050324	24	Hybrid circuit having nanotube electromechanical memory	365/103	
2	<input type="checkbox"/> US 20050062097 A1	20050324	30	Method and system for molecular charge storage field effect transistor	257/324	
3	<input type="checkbox"/> US 20050062062 A1	20050324	93	One-time programmable, non-volatile field effect devices and methods of making same	257/200	
4	<input type="checkbox"/> US 20050048691 A1	20050303	35	High-temperature attachment of organic molecules to substrates	438/99	438/795
5	<input type="checkbox"/> US 20050019500 A1	20050127	22	Attachment of organic molecules to group III, IV or V substrates	427/384	429/213
6	<input type="checkbox"/> US 20040214367 A1	20041029	24	Electromechanical memory array using nanotube ribbons and method for making same	438/53	977/DIG.1
7	<input type="checkbox"/> US 20040214366 A1	20041028	25	Electromechanical memory array using nanotube ribbons and method for making same	438/53	977/DIG.1
8	<input type="checkbox"/> US 20040120180 A1	20040624	19	Variable persistence molecular memory devices and methods of operation thereof	365/151	
9	<input type="checkbox"/> US 20040085805 A1	20040506	24	Device selection circuitry constructed with nanotube technology	365/145	257/E27.004; 257/E27.07; 977/DIG.1
10	<input type="checkbox"/> US 20040007758 A1	20040115	28	Method for conductance switching in molecular electronic junctions	257/522	257/E51.023; 257/E51.047
11	<input type="checkbox"/> US 20030169618 A1	20030911	78	Multistate triple-decker dyads in three distinct architectures for information storage applications	365/151	